

# Timing and tracking with LGAD detectors

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# Time of flight for particle identification

- Particle Separation (dE/dx vs dN/dx) # of sigma K-p u-π momentum spectrum, except for a region around 1 GeV/c 0.1 Momentum [GeV/c] Momentum [GeV/c] in the "blind" region of dE/dx50 ps z<sub>1.0</sub>
- For  $K-\pi$  separation, good performance in most of - A resolution of few tens ps would allow good K- $\pi$  separation
- The IDEA drift chamber is expected to provide PID information based on dE/dx measurement Complementary PID information could be granted by an external time-of-flight detector Timing information would also help relaxing requests on the vertex detector
  - Larger integration time  $\implies$  less power  $\implies$  less material



p (GeV)













The structure can be optimised for high precision timing (Ultra-Fast Silicon Detectors)

- higher gain, smaller thickness
- time resolution of ~30 ps can be obtained

### Low Gain Avalanche Detectors



- Low Gain Avalanche Detectors (LGAD) are reverse-bias, planar, silicon detectors, with an internal gain layer
  - Usually *n*-in-*p* structure, with implanted *p*+ layer
  - High electric field (~300 kV/cm) in narrow region under the junction
  - Moderate gain (~10)  $\Rightarrow$  low noise, segmentation of readout pattern







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### Time resolution of LGAD

Extensive studies have explored sensor configurations:

- active thickness;
- gain layer doping, thickness, depth;



Current productions mostly focusing on 50-µ-thick sensors



FCC France & Italy Workshop

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### LGAD in HEP experiments

LGAD is now a mature technology

- Prototypes from foundries since 2014
- Several qualified manufacturers worldwide



### Both ATLAS and CMS include large LGAD-based timing detectors in their upgrade programs for HL-LHC ATLAS HGTD

- Detectors in pre-production phase
- Parallel development of dedicated front-end electronics









Main effect of radiation damage in LGAD is gain decrease

- Caused by acceptor removal in gain layer
- Can be balanced by raising the bias voltage up to breakdown or single event burnout conditions

- Carbon implantation into the gain layer can slow down the gain decrease process - Extensive tests conducted with different concentration values
- Optimised values can extend lifetime up to a factor 3















## Geometrical efficiency

separate readout electrodes

- $\Rightarrow$  no-gain regions of 50-100 µm between adjacent pads
- $\rightarrow$  not suitable for small pixels
- Fill factor can be significantly reduced by "digging" isolation trenches between pads
  - $\Rightarrow$  no-gain regions of 5-10 µm can be achieved







### Geometrical efficiency ("fill factor") in LGAD is limited by the structures needed to









### **Resistive Silicon Detectors**

- Full geometrical efficiency can be restored in AC-coupled LGADs (AC-LGAD) - readout geometry decoupled from electric field
- A resistive layer is needed as a charge collection path
- $\Rightarrow$  similar concept to gas detectors such as RPCs



 $\Rightarrow$  concetto simile a rivelatori a gas tipo RPC









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## Hit reconstruction in RSD

































Achievable space resolution depends on several factors

- channel pitch;
- electrode geometry;
- electronics noise;
- signal digitisation;
- reconstruction algorithm;



### Jace resolution in RSD







### Resolution of up to 3% of electrode pitch can be achieved

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# Time resolution in RSD

RSD preserve the excellent timing performance of other LGAD sensors

- combined measurement from shared signals;
- additional contribution from propagation delay;
- very good uniformity observed on active area



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### LGAD studies for FCC-ee

Activity started at INFN Genova to investigate the potential of a space-time detector for IDEA based on LGAD technology

Studies on detector simulation, including benchmark channels:

- requirement on detector performance and geometry (granularity);
- possible benefits from use of RSD  $\Rightarrow$  optimisation of electrode geometry

- Tests on LGAD sensors from recent productions, in collaboration with INFN Torino: - set-up for laboratory characterisation of different structures;
- participation at beam tests



